

**EnzyTek**

**EnzyTek Technology , Inc .**

**EnzyTek Technology, Inc.**

7F, No. 35, Hsueh Fu Rd., Hsinchu 300,  
Taiwan , R.O.C.

TEL : 886-3-573-6708 FAX : 886-3-573-8749

**BTA-C1000-2**

# **Preliminary Datasheet**

**Issued date: May 22, 2013**

## EnzyTek Bluetooth® Low Energy Module With on Board Antenna

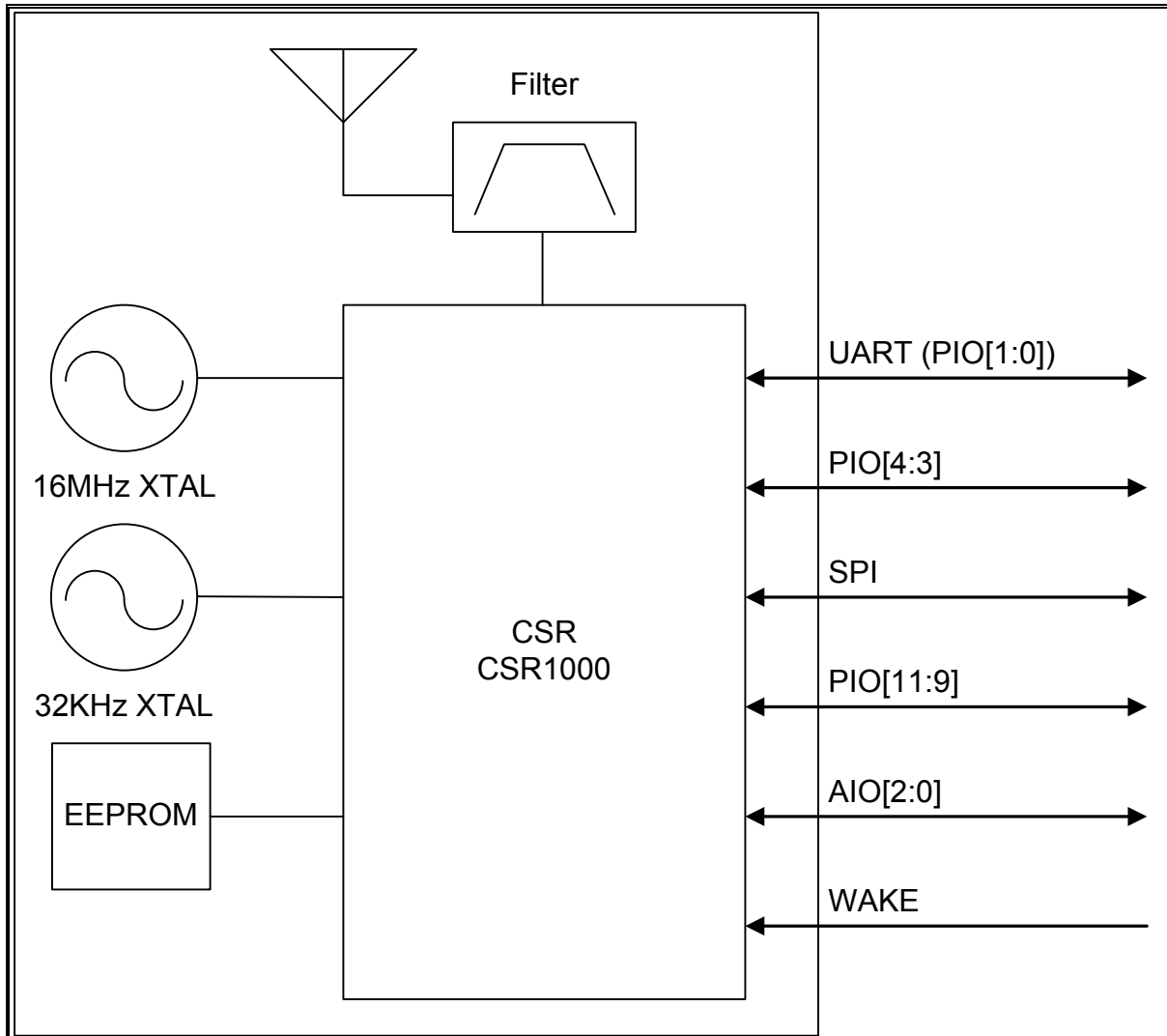
### BTA-C1000-2



### OVERVIEW

- ▶ Highly integration BT 4.0 Low Energy Class II module, CSR CS1000 + Memory + Filter + X'Tal + Chip Antenna.
  - ▶ Wireless communications module conforming to Bluetooth Version 4.0.
  - ▶ UART, SPI interfaces available to various applications.
  - ▶ 5 GPIO ports available for user's application.
  - ▶ 3 Analog IO ports available for user's application.
- 
- ▶ BT Chipset : CSR CSR1000
  - ▶ Standards : Bluetooth 4.0 Low Energy.
  - ▶ Frequency : 2402 ~ 2480 MHz
  - ▶ TX Output Power : 4 dBm (max)
  - ▶ RX Sensitivity : -88 dBm (min)
  - ▶ Range : > 10 m (line-of-sight at open space)
  - ▶ Memory : EEPROM (512K bits)
  - ▶ Operation Voltage : 1.8V ~ 3.6V
  - ▶ Dimension : 18 x 13 x 2.2<sub>(max)</sub> mm<sup>3</sup> (L×W×H)
  - ▶ Environmental Range : Operation Temperature : 0~+70°C, Relative humidity : 0~95%

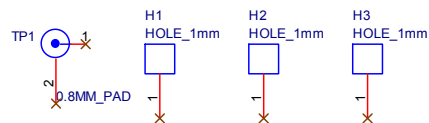
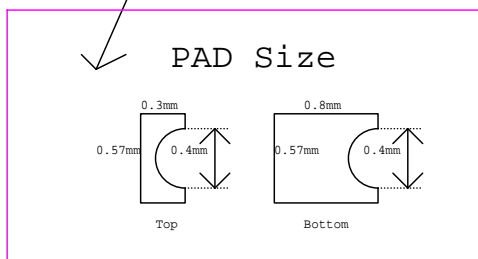
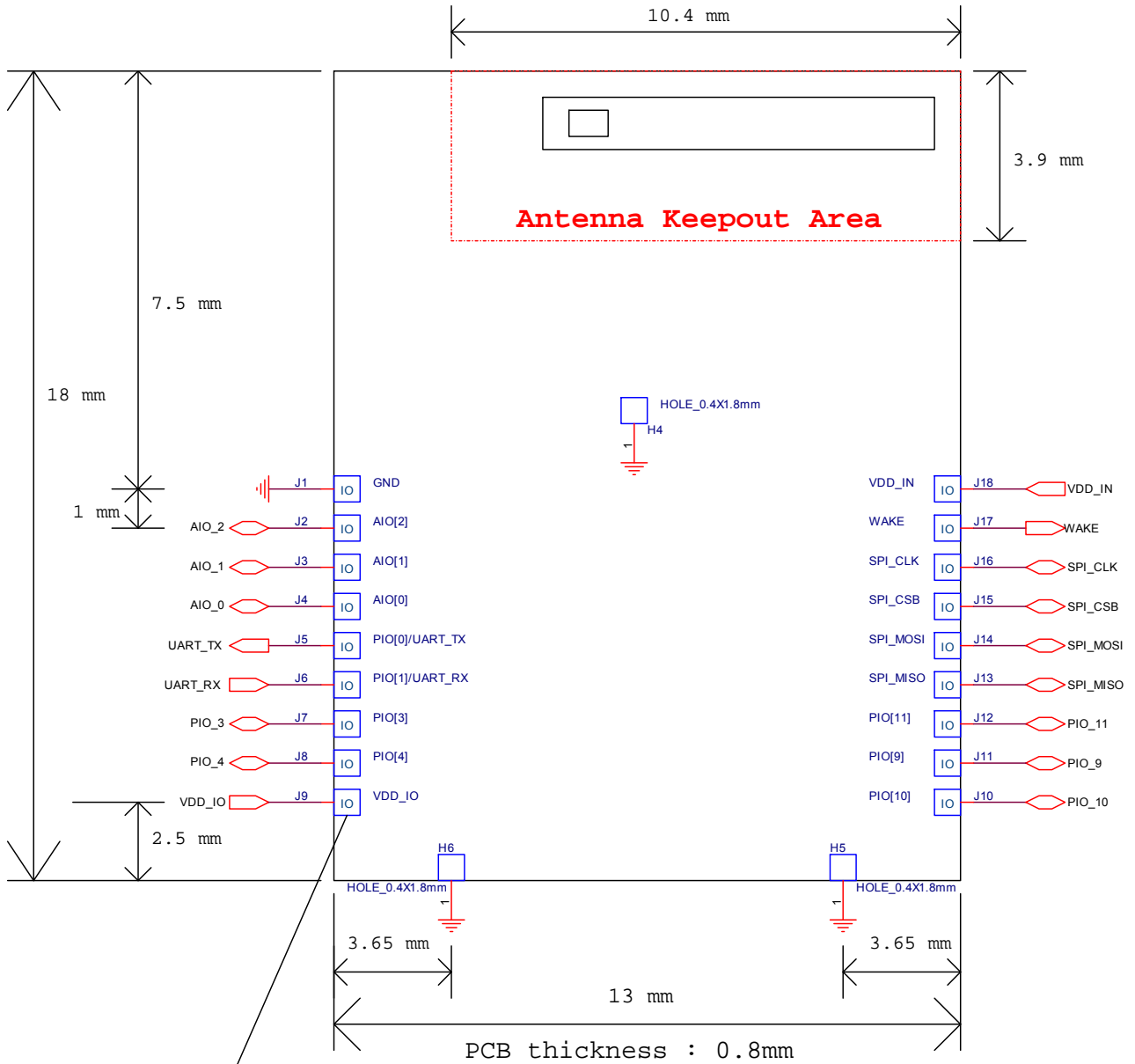
### System Block Diagram



## Pinout Diagram / Dimension

Unit : mm

Note: Please contact EnzyTek to get the detail footprint of the module to do the PCB design.



**I/O PIN LISTING**

<b>Pin No.</b>	<b>Pin Name</b>	<b>Type</b>	<b>Description</b>
J1	GND	Power	Ground
J2	AIO_2	Analog bi-directional	Programmable input/output line
J3	AIO_1	Analog bi-directional	Programmable input/output line
J4	AIO_0	Analog bi-directional	Programmable input/output line
J5	UART_TX (PIO_0)	CMOS output, tri-state, with weak internal pull-up	UART data output t, optional PIO0 which is defined by FW.
J6	UART_RX (PIO_1)	CMOS input with weak internal pull-down	UART data input, optional PIO1 which is defined by FW.
J7	PIO_3	Bi-directional with programmable strength internal pull-up/down	Programmable input/output line
J8	PIO_4	Bi-directional with programmable strength internal pull-up/down	Programmable input/output line
J9	VDD_IO	Power	IO VDD, NC.
J10	PIO_10	Bi-directional with programmable strength internal pull-up/down	Programmable input/output line
J11	PIO_9	Bi-directional with programmable strength internal pull-up/down	Programmable input/output line
J12	PIO_11	Bi-directional with programmable strength internal pull-up/down	Programmable input/output line
J13	SPI_MISO	CMOS output, tri-state, with weak internal pull-down	Serial Peripheral Interface data output
J14	SPI_MOSI	CMOS input with weak internal pull-down	Serial Peripheral Interface data input
J15	SPI_CSB	CMOS input with weak internal pull-up	Chip select for Synchronous Serial Interface active low
J16	SPI_CLK	CMOS input with weak internal pull-down	Serial Peripheral Interface clock
J17	WAKE	Input has no internal pull-up or pull-down, use external pull-down.	Input to wake the module from hibernate or dormant.
J18	VDD_IN	Power	3.3V input

**Electrical Characteristics****Absolute Maximum Ratings :**

	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Supply Voltage	-	-	3.6	V
Storage Temperature	-40	-	85	°C

**Recommend Operation Conditions :**

	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Supply Voltage	1.8	-	3.6	V
Storage Temperature	0	-	70	°C

**Input/Output Terminal Characteristics :**

	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Digital (UART, PIO)				
V <sub>IL</sub> Input Voltage Low	-0.4	-	+0.4	V
V <sub>IH</sub> Input Voltage High	0.7xVDD	-	VDD+0.4	V
V <sub>OL</sub> Output Voltage Low, (I <sub>O</sub> is 4mA)	-	-	0.4	V
V <sub>OH</sub> Output Voltage High, (I <sub>O</sub> is -4mA)	0.75xVDD	-	-	V

## Radio Characteristics

VCC = 3.3V

	Min	Typ	Max	Limits(BLE SPEC)	Unit
Output Power					
Max Power	4			<10	dBm
Min Power	-20			>-20	dBm
Peak to Average		0		<3	dBm
Carrier drift					
Fn	-150		150	<=150	kHz
Drift rate	-20		20	<20	kHz/50us
Max Power	-50		50	<50	kHz
Modulation Characteristic					
F1avg,'F1max'	225		275	225<= <=275	kHz
F2avg,'F2max'	185			>=185	kHz
F1/F2 Ratio		0.8		>=0.8	
Sensitivity (-88dBm)					
Frame Error Rate	0		30.8	<=30.8(-70dBm)	%
PER Integrity					
Frame Error Rate	50		65.4	50<= <=65.4	%
Max Input Power					
Frame Error Rate		0		<=30.8(-40dBm)	%

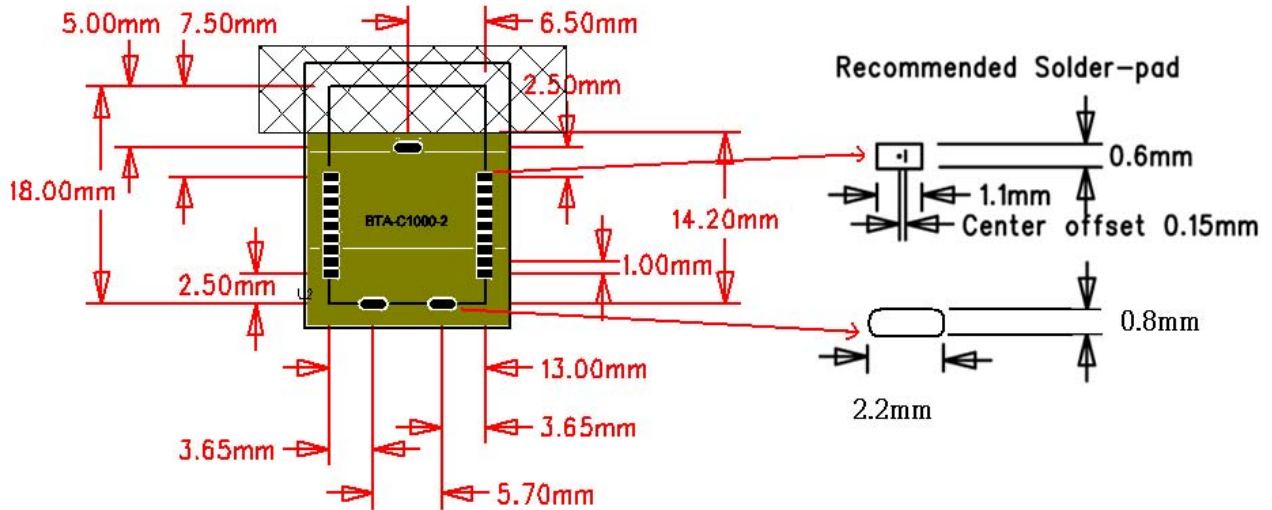
**Current Consumption**

<b>HW</b>	BTM-C1000-2	
<b>FW version</b>	F-Serial_Port-v003	
<b>FW configuration</b>	Role	Gatt Server, device side
	Service	SPS Service
	Baud Rate	2400
	Default Power	Scale 0
<b>BT BLE Host</b>	iPhone 4S (ios5)	
<b>Current Meter</b>	Fluke 189	

	<b>Min.</b>	<b>Avg.</b>	<b>Max.</b>
<b>Power On No connection</b>	5.93 uA	6.79 uA	39.90uA
<b>Power On advertising</b>	202 uA	365 uA	567 uA
<b>Connected No Data Transfer</b>	15 uA	69 uA	143 uA
<b>Connected TX Data/sec (from module to host)</b>	17 uA	184 uA	1210 uA
<b>Connected TX Data/500ms (from module to host)</b>	17 uA	275 uA	1213 uA



### PCB Layout Guide



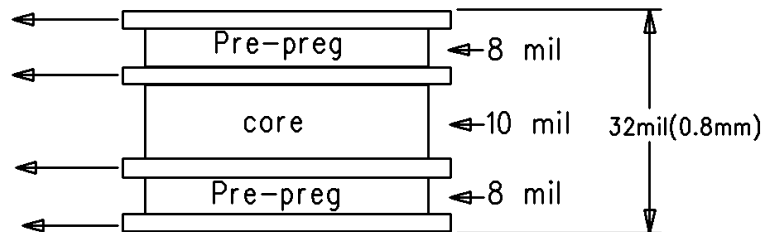
#### The 4-Layer Stackup

Component side(Layer 1), 1oz Cu.

GND side(Layer 2), 1oz Cu.

VCC/GND side(Layer 3), 1oz Cu.

Bottom side (Layer 4), 1oz Cu.



Material : FR4

DR=4.2+/-10%@1GHz and,DF=0.014+/-10%@1GHz

CPWG - 50-ohm Transmission Line: Gap=10mil, W=14mil

### Application Schematic

